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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









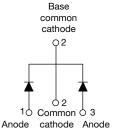
www.vishay.com

Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 8 A

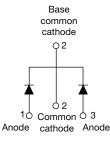
VS-16CTQ...SPbF











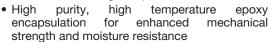
D²PAK

TO-262

PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	2 x 8 A
V _R	60 V, 80 V, 100 V
V _F at I _F	0.58 V
I _{RM}	7 mA at 125 °C
T _J max.	175 °C
Diode variation	Common cathode
E _{AS}	7.5 mJ

FEATURES

- 175 °C T_J operation
- · Center tap configuration
- Low forward voltage drop





ROHS COMPLIANT HALOGEN

FREE

- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	16	A				
V _{RRM}		60 to 100	V				
I _{FSM}	t _p = 5 μs sine	850	A				
V _F	8 A _{pk} , T _J = 125 °C (per leg)	0.58	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-16CTQ060SPbF VS-16CTQ100SPbF VS-16CTQ100SPbF VS-16CTQ100SPbF VS-16CTQ100-1PbF VS-16CTQ100-1PbF							
Maximum DC reverse voltage	V _R	60	80	100	\/		
Maximum working peak reverse voltage	V_{RWM}	00	00	100	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average per leg				8		
forward current See fig. 5 per device	I _{F(AV)}	50 % duty cycle at T_C = 148 °C, rectangular waveform		16	А	
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	850		
non-repetitive surge current per leg See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse condition and with rated V _{RRM} applied		275	А	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		0.50	А	



VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		8 A	T _{.1} = 25 °C	0.72		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	16 A	1J=25 C	0.88	V	
See fig. 1	VFM (1)	8 A	T _{.1} = 125 °C	0.58		
		16 A	1 J = 125 C	0.69		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.55	mA	
See fig. 2		T _J = 125 °C		7.0		
Threshold voltage	V _{F(TO)}	T T mayimum		0.415	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		11.07	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		500	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nΗ	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to case per leg		D	DC operation	3.25	
Maximum thermal resistance, junction to case per package		R_{thJC}	DC operation	1.63	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Manustina taurus	minimum			6 (5)	kgf · cm
Mounting torque —	maximum			12 (10)	(lbf \cdot in)
Mayling davide			Case style D ² PAK	16CT	QS
Marking device			Case style TO-262	16CT	Q1

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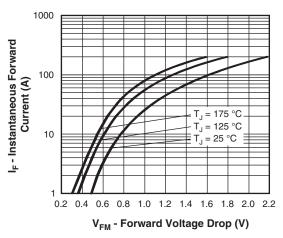


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

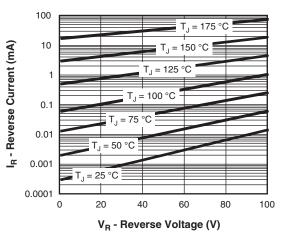


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

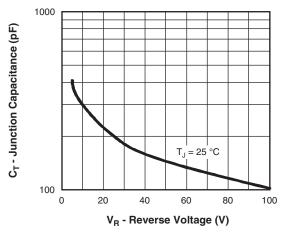


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

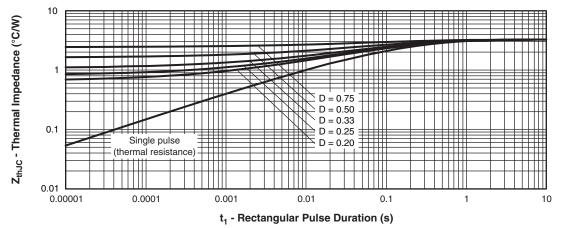


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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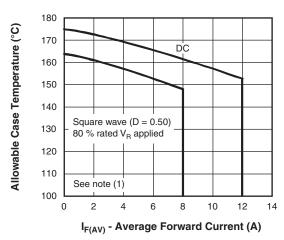


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

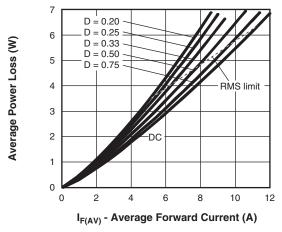


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

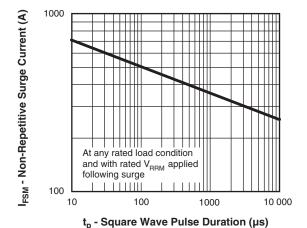


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

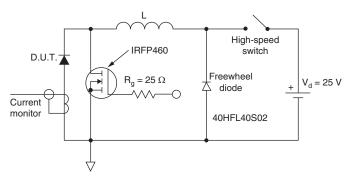


Fig. 8 - Unclamped Inductive Test Circuit

Note

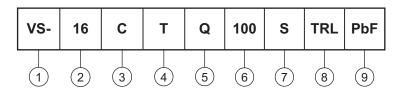
[1] Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse$ power loss $= V_{R1} \times I_{R}$ (1 - D); I_{R} at $V_{R1} = 80$ % rated V_{R} applied

VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product suffix

2 - Current rating (16 A)

3 - Circuit configuration: C = Common cathode

4 - T = TO-220

5 - Schottky "Q" series

Schottky "Q" series 060 = 60 V Voltage ratings 080 = 80 V 100 = 100 V

7 - • S = D²PAK

• -1 = TO-262

8 - None = Tube (50 pieces)

• TRL = Tape and reel (left oriented - for D²PAK only)

• TRR = Tape and reel (right oriented - for D²PAK only)

9 - PbF = Lead (Pb)-free

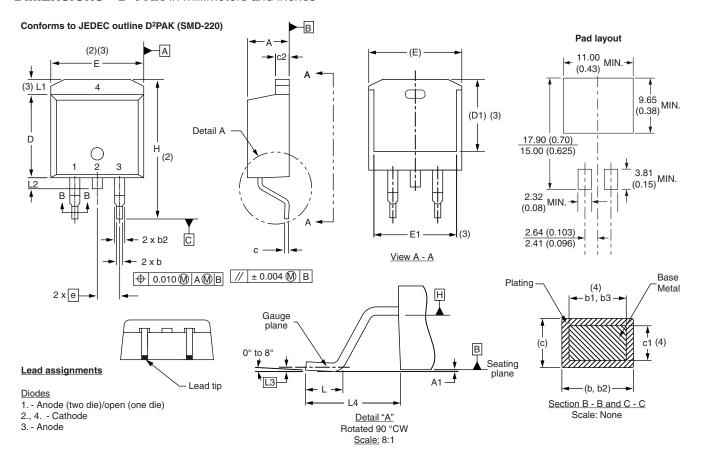
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95014</u>						
Part marking information	www.vishay.com/doc?95008					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95279					



Vishay Semiconductors

D²**PAK**, **TO**-262

DIMENSIONS - D²PAK in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	NOTES	
STIMBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INC	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

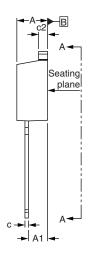
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

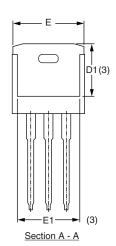
(7) Outline conforms to JEDEC outline TO-263AB

D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches





⊕ 0.010 M AM B

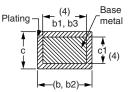
Lead assignments



Diodes

1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIMETERS		INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	2.54 BSC) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- $^{(1)}$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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Vishay

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